

20V N-CHANNEL ENHANCEMENT MODE MOSFET IN SOT23

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D Max (Note 5)
20V	175mΩ @ V _{GS} = 4.5V	1.40A @ T _A = 25°C
	240mΩ @ V _{GS} = 2.5V	1.20A @ T _A = 25°C
	360mΩ @ V _{GS} = 1.8V	1.0A @ T _A = 25°C

Features and Benefits

- On resistance <200mΩ
- Low Gate Threshold Voltage
- Fast Switching Speed
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- ESD Protected Gate 2kV
- Qualified to AEC-Q101 Standards for High Reliability

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Load switch

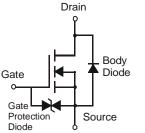
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin
- Weight: 0.08 grams (approximate)

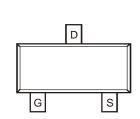




Top View







Top View

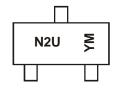
Ordering Information (Note 3)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN2300U-7	N2U	7	8	3000

Notes:

- 1. No purposefully added lead
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.
- 3. For packaging details, go to our website at http://www.diodes.com.

Marking Information

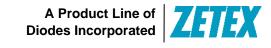


N2U = Product Type Marking Code YM = Date Code Marking Y = Year (ex: Y = 2011) M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α	[3	С		D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





Maximum Ratings @ $T_A = 25$ °C unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current	Steady T _A = 25°C (Note 5)		I _D	1.40 1.01 1.24	А
Pulsed Drain Current (Note 6)		I _{DM}	11	Α	

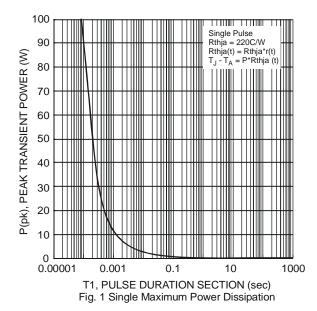
Thermal Characteristics @TA = 25°C unless otherwise specified

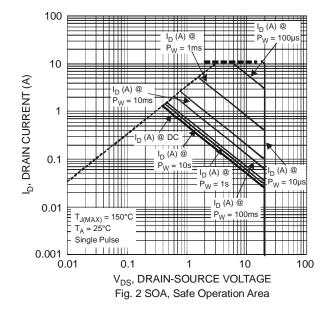
Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 4)	Б	0.43	W
Power Dissipation	(Note 5)	PD	P _D 0.55	
Thermal Decistores, Junction to Ambient	(Note 4)		288	°C/W
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0JA}	228	°C/W
Operating and Storage Temperature Range	T_J , T_{STG}	-55 to +150	°C	

Notes:

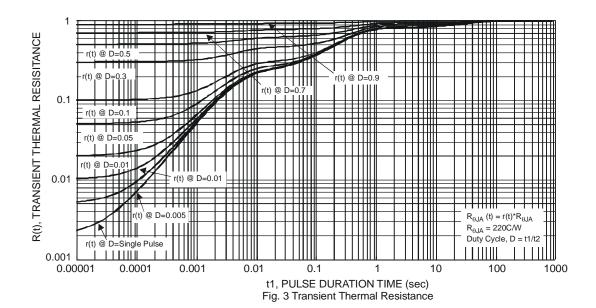
- 4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout
- 5. Device mounted on 25mm X 25mm square copper plate with FR-4 substrate PC board, 2oz copper
- 6. Device mounted on minimum recommended pad layout test board, 10μs pulse duty cycle = 1%.

Thermal Characteristics







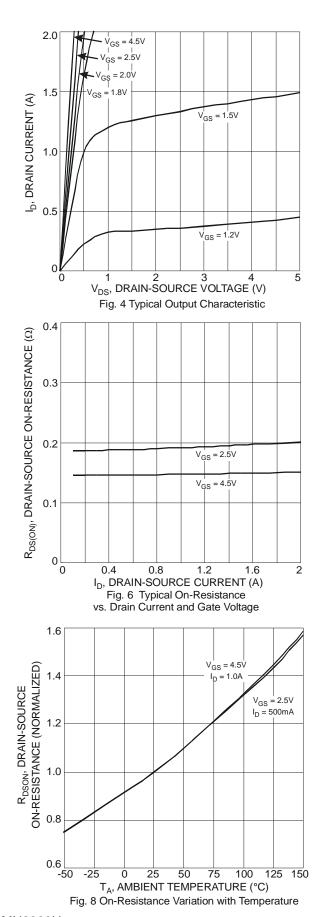


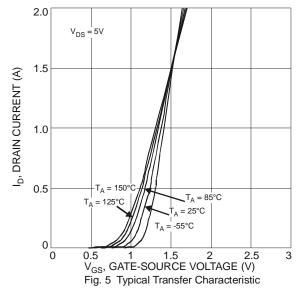
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	1	μΑ	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	10	μΑ	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						_	
Gate Threshold Voltage	$V_{GS(th)}$	0.45	-	0.95	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
				175		$V_{GS} = 4.5V, I_D = 300mA$	
Static Drain-Source On-Resistance	R _{DS (ON)}	-		240	mΩ	$V_{GS} = 2.5V, I_D = 250mA$	
	, ,			360		$V_{GS} = 1.8V, I_D = 100mA$	
Forward Transfer Admittance	Y _{fs}	40	-	-	mS	$V_{DS} = 3V$, $I_D = 30mA$	
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_S = 300mA$	
DYNAMIC CHARACTERISTICS (Note 7)				-			
Input Capacitance	C _{iss}	-	64.3	-	pF), OF),), O),	
Output Capacitance	Coss	-	6.1	-	pF	$V_{DS} = 25V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	4.5	-	pF	1 = 1.000112	
Gate Resistance	Rg	-	70	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qq	-	1.6	-	nC	451414	
Gate-Source Charge	Q _{qs}	-	0.2	-	nC	$V_{GS} = 4.5V, V_{DS} = 15V,$	
Gate-Drain Charge	Q_{qd}	-	0.2	-	nC	- I _D = 1A	
Turn-On Delay Time	t _{D(on)}	-	3.5	-	ns		
Turn-On Rise Time	t _r	-	2.8	-	ns	$V_{DS} = 10V, I_{D} = 1A$	
Turn-Off Delay Time	t _{D(off)}	-	38	-	ns	$V_{GS} = 10V, R_G = 6\Omega$	
Turn-Off Fall Time	t _f	-	13	-	ns]	

Notes: 7. Short duration pulse test used to minimize self-heating effect.







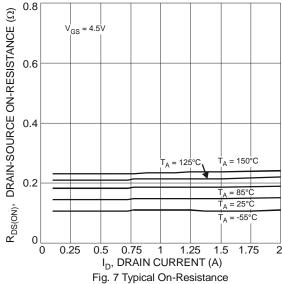
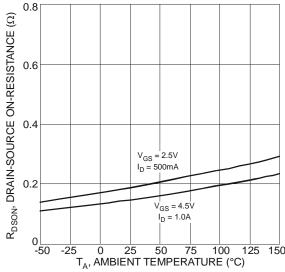


Fig. 7 Typical On-Resistance vs. Drain Current and Temperature





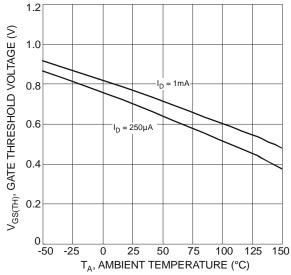
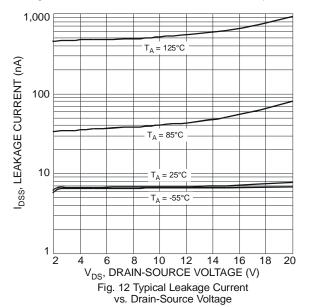
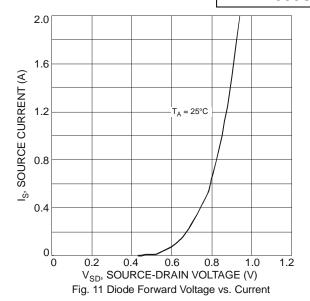


Fig. 10 Gate Threshold Variation vs. Ambient Temperature



8 V_{DS} = 15V V_{DS} = 15V V_{DS} = 15V V_{DS} = 1A V_{DS} = 15V V_{DS} = 15V



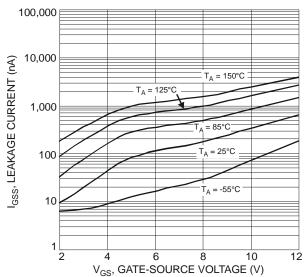
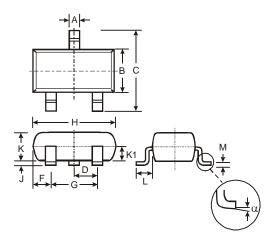


Fig.13 Leakage Current vs. Gate-Source Voltage

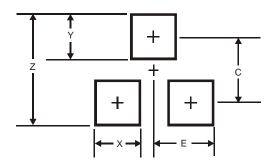


Package Outline Dimensions



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	1	0.400				
L	0.45	0.61	0.55				
M	0.085	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





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